

# Asafuji Ryosuke

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/6642552/publications.pdf>

Version: 2024-02-01

3  
papers

23  
citations

2258059

3  
h-index

2550090

3  
g-index

3  
all docs

3  
docs citations

3  
times ranked

24  
citing authors

#	ARTICLE	IF	CITATIONS
1	Si and C emission into the oxide layer during the oxidation of silicon carbide and its influence on the oxidation rate. AIP Advances, 2015, 5, .	1.3	11
2	Photoluminescence study of oxidation-induced faults in 4H-SiC epilayers. AIP Advances, 2015, 5, .	1.3	8
3	Generation of stacking faults in 4H-SiC epilayer induced by oxidation. Materials Research Express, 2018, 5, 015903.	1.6	4